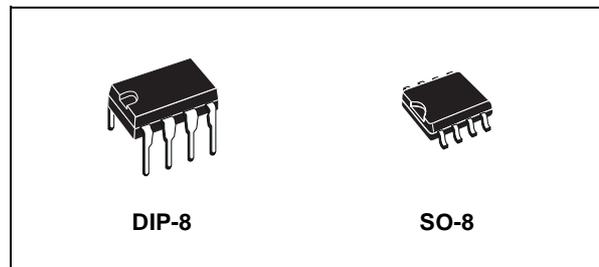




ST735S ST735T

300kHz, -5V/ADJ INVERTING, NEGATIVE OUTPUT CURRENT-MODE PWM REGULATOR

- CONVERTS +4.0V TO + 6.2V INPUT TO -5V OUTPUT (735S) OR +3.5V TO + 9.0V TO A NEGATIVE ADJUSTABLE OUTPUT (735T)
- 1W GUARANTEED OUTPUT POWER
- 72% TYPICAL EFFICIENCY
- 0.8mA QUIESCENT CURRENT
- 1μA SHUTDOWN MODE
- 300KHZ FIXED FREQUENCY OSCILLATOR
- CURRENT MODE PWM CONVERTER
- LOW NOISE AND JITTER
- SOFT START
- SIMPLE APPLICATION CIRCUIT
- UNDERVOLTAGE LOCKOUT (735S)



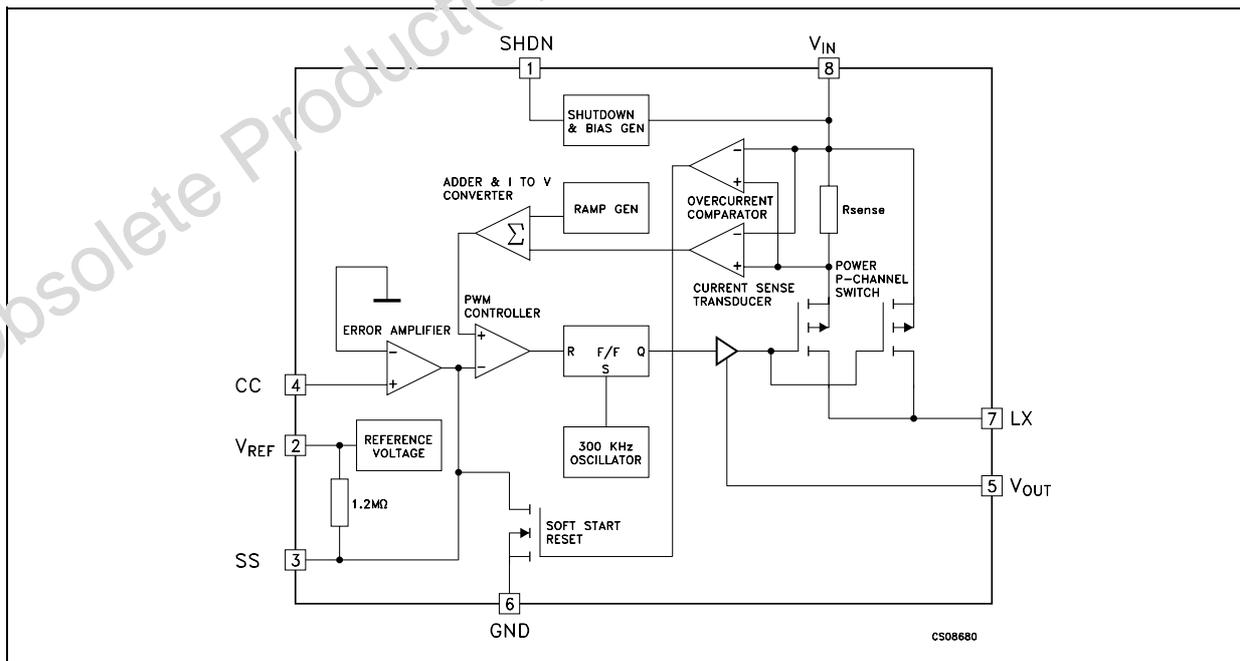
0.8mA and, in shutdown mode it is reduced to 1μA.

These power-conserving features, along with high efficiency and applications circuits, that lend itself to minaturization, make the ST735S/ST735T excellent in a broad range of on-card, HDD and portable equipment applications. These device employ a high performance current mode pulse with modulation (PWM) control scheme to provide tight output voltage regulation and low noise. The fixed frequency oscillator is factory trimmed to 300kHz, allowing for easy noise filtering. The regulator in production is tested to guarantee an output accuracy within $\pm 5\%$ over all specified conditions.

DESCRIPTION

The ST735S/ST735T is a Bi-CMOS, inverting switch mode DC-DC regulator with internal Power MOSFET that generates a fixed -5V (S version) or a negative adjustable (T version) output voltage from a 4V (3.5V for the 735T) to 6.2V input voltage (9V for the 735T); is guaranteed an output current of 200mA for inputs greater than 4.5V. The quiescent current for this device is typically of

SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit | |
|-----------|---|----------------------|-------------|----|
| V_{IN} | DC Input Voltage (V_{IN} to GND) for ST735S | -0.3 to +7 | V | |
| V_{IN} | DC Input Voltage (V_{IN} to GND) for ST735T (Note 1) | -0.3 to +11 | V | |
| SHDN | Shutdown Voltage (SHDN to GND) | -0.3 to $V_{IN}+0.3$ | V | |
| V_{LX} | Switch Voltage (Lx to V_{IN}) | -12.5 to +0.3 | V | |
| V_{FB} | Feedback Voltage (V_{OUT} to GND) | -11 to +0.3 | V | |
| V_{OUT} | Output Voltage (V_{OUT} to GND) | -11 to +0.3 | V | |
| | Other Input Voltage (SS, CC to GND) | -0.3 to $V_{+}+0.3$ | V | |
| I_{LX} | Peack Switch Current | 2 | A | |
| P_{tot} | Power Dissipation at $T_j = 70^{\circ}C$ | DIP-8 | 725 | mW |
| | | SO-8 | 470 | |
| T_{stg} | Storage Temperature Range | -55 to +150 | $^{\circ}C$ | |
| T_{op} | Operating Junction Temperature Range | -40 to +125 | $^{\circ}C$ | |

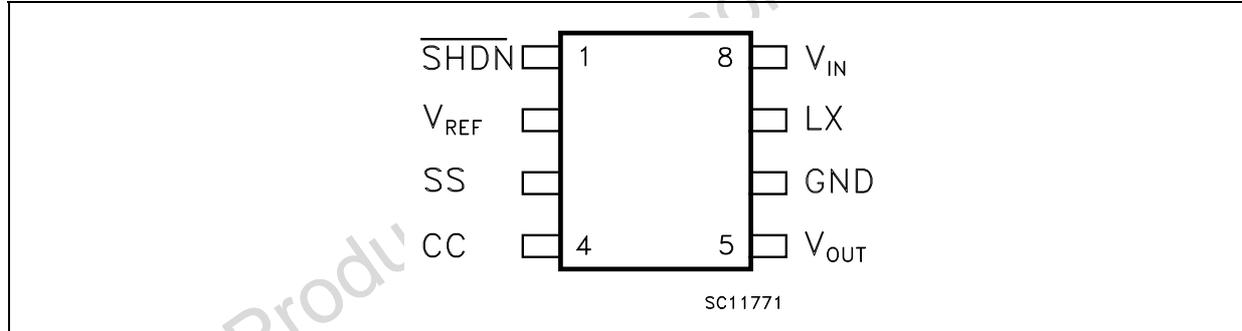
Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

Note 1: The input to output differential voltage is limited to $V_{IN}+|V_{OUT}|<12.7V$

THERMAL DATA

| Symbol | Parameter | DIP-8 | SO-8 | Unit |
|----------------|----------------------------------|-------|------|---------------|
| $R_{thj-case}$ | Thermal Resistance Junction-case | 2 | 8 | $^{\circ}C/W$ |

CONNECTION DIAGRAM (top view)



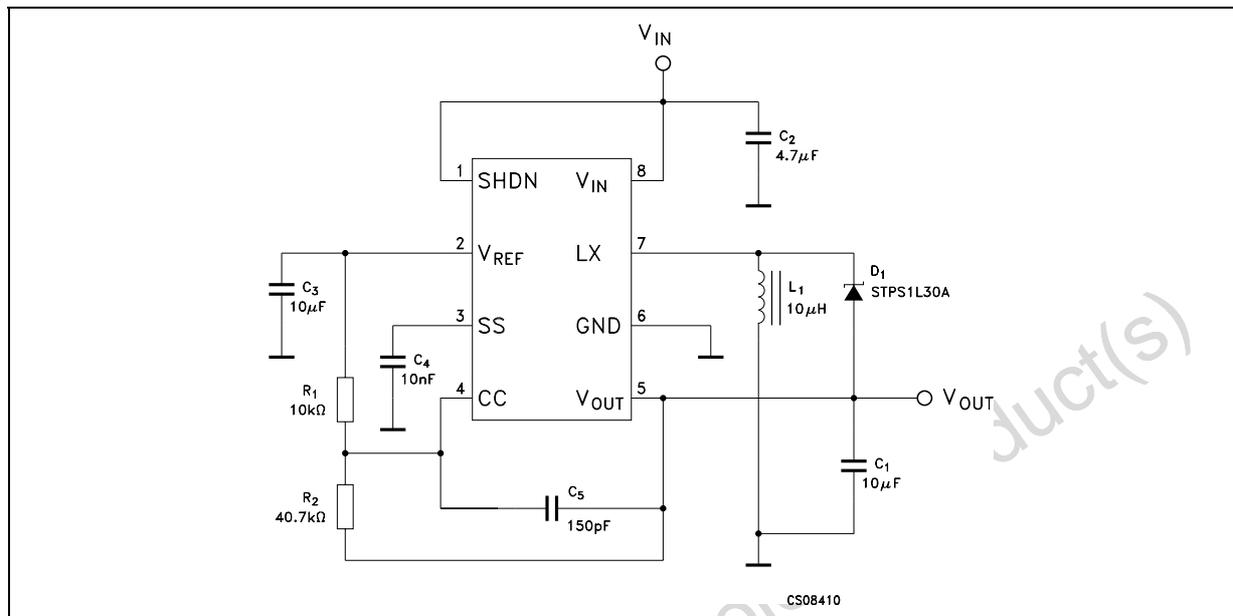
PIN DESCRIPTION

| Pin N° | Symbol | Name and Function |
|--------|-----------|---|
| 1 | SHDN | SHUT-DOWN Control ($V_{CC}=ON$ GND=Shutdown) |
| 2 | V_{REF} | Reference Output Voltage |
| 3 | SS | Soft Start |
| 4 | CC | Compensation Input |
| 5 | V_{OUT} | Negative Output Voltage |
| 6 | GND | Ground |
| 7 | LX | Switch Output |
| 8 | V_{IN} | Positive Supply - Voltage Input |

ORDERING CODES

| TYPE | DIP-8 | SO-8 | SO-8 (T&R) |
|--------|----------|----------|-------------|
| ST735S | ST735SCN | ST735SCD | ST735SCD-TR |
| ST735T | ST735TCN | ST735TCD | ST735TCD-TR |

TYPICAL APPLICATION CIRCUIT



NOTE:

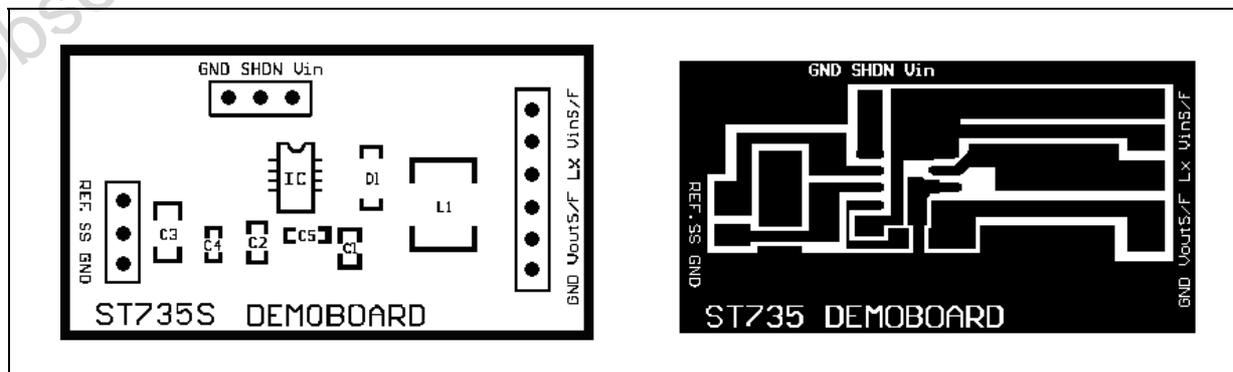
- 1) All capacitors are X7R ceramic
- 2) C₅ can be omitted if are used higher values for the input and output capacitors (suggested C₂=47µF, C₁=100µF).
- 3) R₁ and R₂ must be placed is ST735T applications only. Their values are calculated by the following formula $R_2 = (V_{OUT}/V_{REF}) \times R_1$. For R₁ can be chosen any value between 2kΩ and 20kΩ

APPLICATION CIRCUIT

To achieve the best performances from switching power supply topology, particular care to layout drawing is needed, in order to minimize EMI and obtain low noise. Moreover, jitter free operation ensures the full device functionality. Layout design proposed on demoboard helps to lower the developing time. Wire lengths must be minimized,

filter and bypass capacitors must be low ESR type, placed as close as possible to the integrated circuit. The 4.7µF (or 6.8µF) inductor must be chosen built on a core, taking care that saturation current should be higher than the peak LX switch current. See the Peak Inductor Current vs Output Current graph.

PRINTED DEMOBOARD (not in scale)



ST735S/ST735T

ELECTRICAL CHARACTERISTICS OF ST735S (Refer to test circuit, $V_{IN}=5V$, $C_{IN} = 4.7\mu F$, $C_{OUT} = 10\mu F$ all X7R ceramic, $L = 4.7\mu H$ (Note1) , $I_{OUT}=0mA$, $T_{amb} = -40$ to $125^{\circ}C$, unless otherwise specified. Typical value are referred at $T_{amb}= 25^{\circ}C$)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|------------------|--------------------------------------|---|-------|-------|-------|------------------|
| V_{IN} | Input Voltage | | 4 | | 6.2 | V |
| V_{OUT} | Output Voltage | $V_{IN} = 4.5V$ to $6.2V$ $I_{OUT} = 0$ to $200mA$ $T_{amb} = -40$ to $125^{\circ}C$ | -5.25 | -5 | -4.75 | V |
| | | $V_{IN} = 4.0V$ to $6.2V$ $I_{OUT} = 0$ to $175mA$ $T_{amb} = -40$ to $125^{\circ}C$ | -5.25 | -5 | -4.75 | V |
| I_{OUT} | Output Current | $V_{IN} = 4.5V$ to $6.2V$ $T_J = 0$ to $125^{\circ}C$ | 200 | 275 | | mA |
| | | $V_{IN} = 4.5V$ to $6.2V$ $I_{OUT} = 0$ to $175mA$ $T_{amb} = -40$ to $125^{\circ}C$ | 175 | | | mA |
| | | $V_{IN} = 4.0V$ $V_{OUT} = -5V$ | | 175 | | mA |
| I_{SUPPLY} | Supply Current | Includes Switch Current | | 0.8 | 1.6 | mA |
| $I_{STANDBY}$ | Standby Current | $V_{SHDN} = 0V$ | | 1 | 10 | μA |
| I_{SC} | Short Circuit Current | $V_{IN} = 5V$ | | 0.9 | | A |
| I_{PEAK} | LX Max Peak Current | (Note 2) | | 1.5 | | A |
| V_{LO} | Undervoltage Lock-out | | | 3.5 | 4 | V |
| ΔV_{OUT} | Line Regulation | $V_{IN} = 4.0V$ to $6.2V$ | | 0.1 | | %/V |
| ΔV_{OUT} | Load Regulation | $I_{OUT} = 0$ to $200mA$ | | 0.003 | | %/mA |
| V_{REF} | Reference Voltage | $T_{amb} = 25^{\circ}C$ (Note 3) | | 1.225 | | V |
| ΔV_{REF} | Reference Drift | $T_{amb} = -40$ to $125^{\circ}C$ | | 50 | | ppm/ $^{\circ}C$ |
| R_{DSON} | LX ON Voltage | | | 0.5 | | Ω |
| I_{LEAK} | LX Leakage Current | $V_{DS} = 10V$ | | 1 | | μA |
| I_{SH} | Shutdown Pin Current | | | | 1 | μA |
| V_{IL} | Shutdown Input Low Threshold | | | | 0.25 | V |
| V_{IH} | Shutdown Input High Threshold | | 2 | | | V |
| f_{OSC} | Maximum Oscillator Frequency | | | 300 | | KHz |
| η | Efficiency | $I_{OUT} = 100mA$ | | 72 | | % |
| R_{CC} | Compensation Pin Impedance on CC Pin | | | 7.5 | | K Ω |

Note 1: Utilize of $6.8\mu H$ permits to reach higher current capability at the same operating conditions

Note2: Guaranteed by design, but not tested in production

Note3 : Tested at $I_{VREF} = 125\mu A$

ELECTRICAL CHARACTERISTICS OF ST735T (Refer to test circuit, $V_{IN}=5V$, $C_{IN} = 4.7\mu F$, $C_{OUT} = 10\mu F$ all X7R ceramic, $L = 4.7\mu H$ (Note1) , $I_{OUT}=0mA$, V_O adjusted to $-5V$, $T_{amb} = -40$ to $125^\circ C$, unless otherwise specified. Typical value are referred at $T_{amb}= 25^\circ C$)

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|------------------|--------------------------------------|--|-------|-------|-------|-----------------|
| V_{IN} | Input Voltage | | 3.5 | | 9 | V |
| V_O | Output Voltage | $V_{IN} = 4.5V$ to $6.2V$ $I_{OUT} = 0$ to $200mA$ $T_{amb} = -40$ to $125^\circ C$ | -5.25 | -5 | -4.75 | V |
| | | $V_{IN} = 4.0V$ to $6.2V$ $I_{OUT} = 0$ to $175mA$ $T_{amb} = -40$ to $125^\circ C$ | -5.25 | -5 | -4.75 | V |
| I_O | Output Current | $V_{IN} = 4.5V$ to $6.2V$ $T_{amb} = 0$ to $125^\circ C$ | 200 | 275 | | mA |
| | | $V_{IN} = 4.5V$ to $6.2V$ $I_{OUT} = 0$ to $175mA$ $T_{amb} = -40$ to $125^\circ C$ | 175 | | | mA |
| | | $V_{IN} = 4.0V$ $V_{OUT} = -5V$ | | 175 | | mA |
| I_{SUPPLY} | Supply Current | Includes Switch Current | | 0.8 | 1.6 | mA |
| $I_{STANDBY}$ | Standby Current | $V_{SHDN} = 0V$ | | 1 | 10 | μA |
| I_{SC} | Short Circuit Current | $V_{IN} = 5V$ | | 0.9 | | A |
| I_{PEAK} | LX Max Peak Current | (Note 2) | | 1.5 | | A |
| V_{LO} | Undervoltage Lock-out | | | 3.5 | 4 | V |
| ΔV_{OUT} | Line Regulation | $V_{IN} = 4.0V$ to $6.2V$ | | 0.1 | | %/V |
| ΔV_{OUT} | Load Regulation | $I_{OUT} = 0$ to $200mA$ | | 0.003 | | %/mA |
| V_{REF} | Reference Voltage | $T_{amb} = 25^\circ C$ (Note 3) | | 1.225 | | V |
| ΔV_{REF} | Reference Drift | $T_{amb} = -40$ to $125^\circ C$ | | 50 | | ppm/ $^\circ C$ |
| R_{DSON} | LX ON Voltage | | | 0.5 | | Ω |
| I_{LEAK} | LX Leakage Current | $V_{DS} = 10V$ | | 1 | | μA |
| I_{SH} | Shutdown Pin Current | | | | 1 | μA |
| V_{IL} | Shutdown Input Low Threshold | | | | 0.25 | V |
| V_{IH} | Shutdown Input High Threshold | | 2 | | | V |
| f_{OSC} | Maximum Oscillator Frequency | | | 300 | | KHz |
| ν | Efficiency | $I_{OUT} = 100mA$ | | 72 | | % |
| R_{CC} | Compensation Pin Impedance on CC Pin | | | 7.5 | | $K\Omega$ |

Note 1: Utilize of $6.8\mu H$ permits to reach higher current capability at the same operating conditions

Note2: Guaranteed by design, but not tested in production

Note3 : Tested at $I_{VREF} = 125\mu A$

TYPICAL CHARACTERISTICS (Referred to typical application circuit, $T_{amb}=25^{\circ}\text{C}$ unless otherwise specified)

Figure 1 : Output Voltage vs Temperature

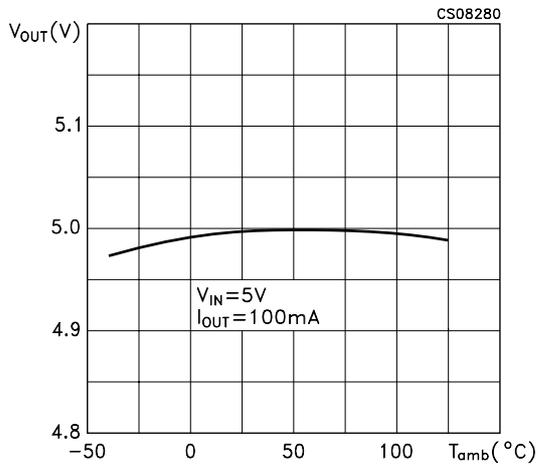


Figure 2 : Reference Voltage vs Temperature

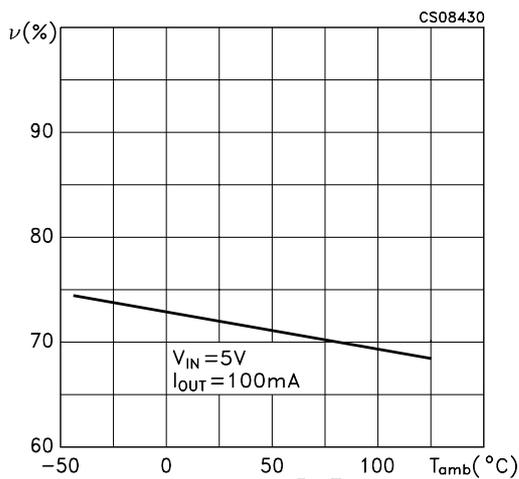


Figure 3 : Efficiency vs Temperature

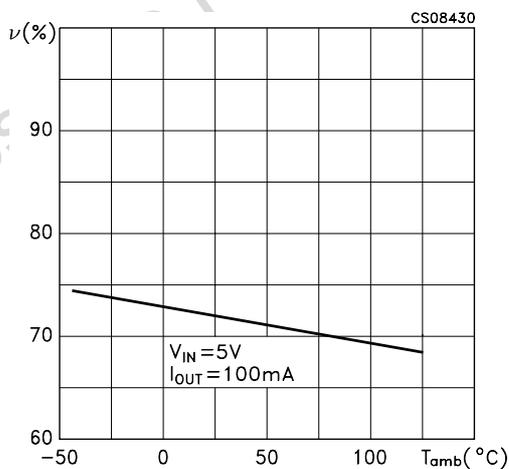


Figure 4 : Efficiency vs Ouput Current

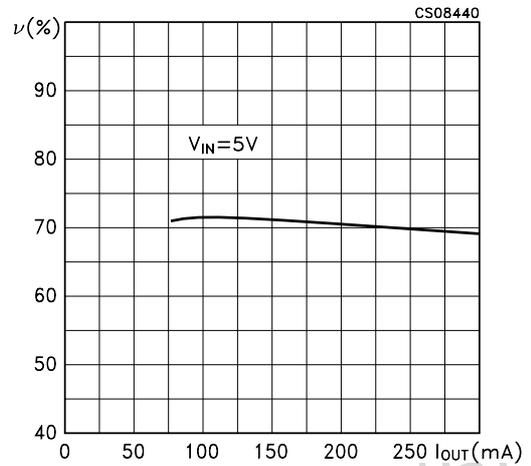


Figure 5 : Efficiency vs Low Ouput Current

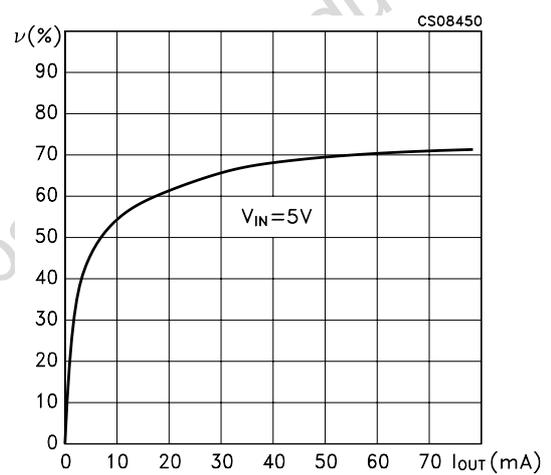


Figure 6 : Supply Current vs Temperature

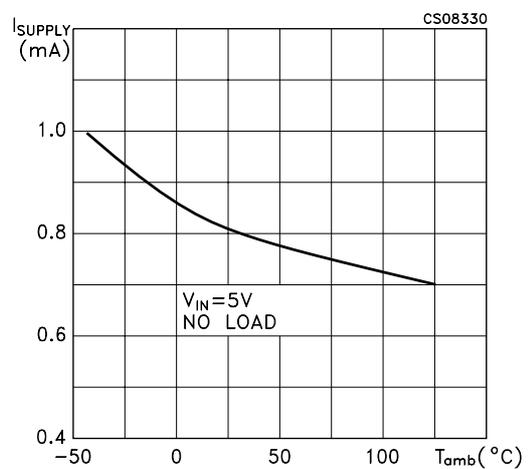


Figure 7 : Supply Current vs Input Voltage for ST735S

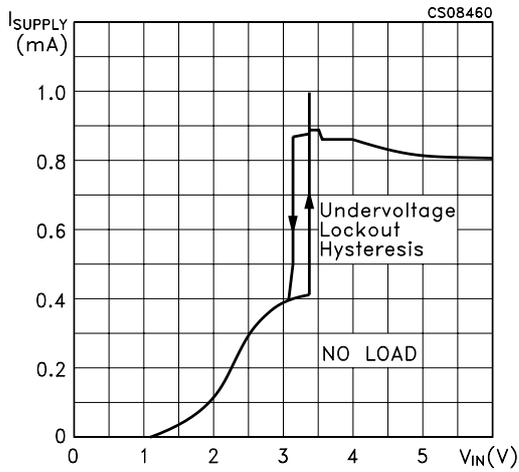


Figure 10 : Peak Inductor vs Output Current

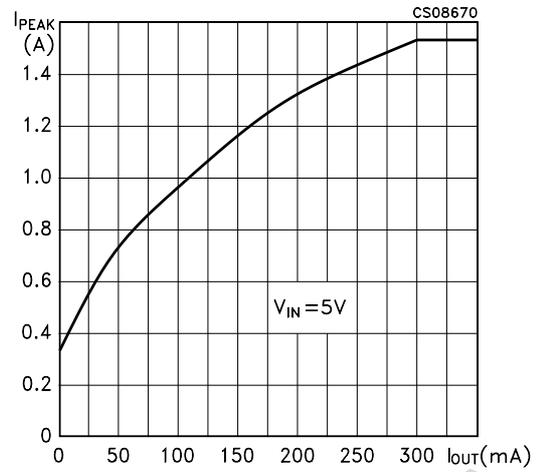


Figure 8 : Supply Current vs Input Voltage for ST734T

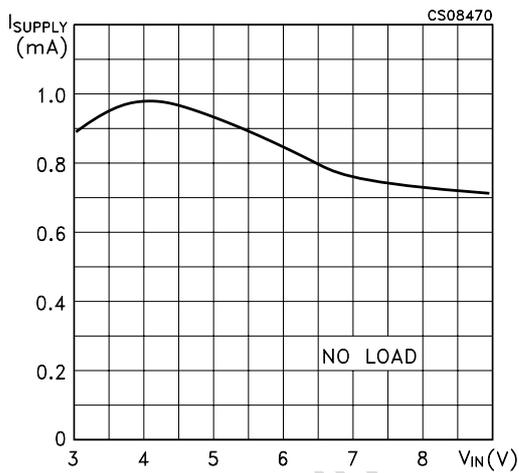


Figure 11 : Switch Current Limit vs Soft Start Voltage

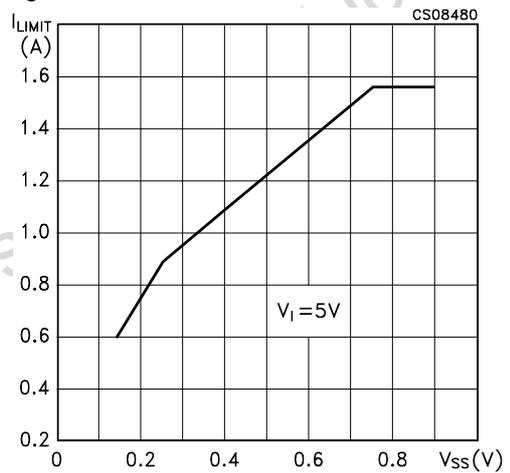


Figure 9 : Shutdown Threshold vs Temperature

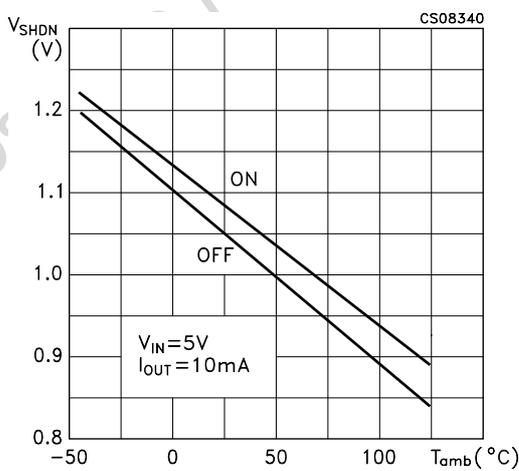


Figure 12 : Oscillator Frequency Vs Temperature

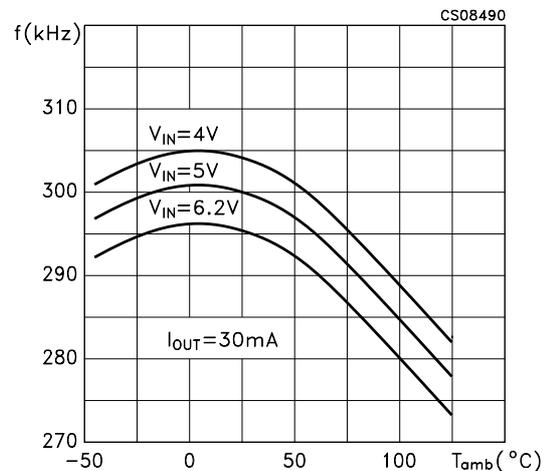


Figure 13 : LX On Resistance vs Temperature

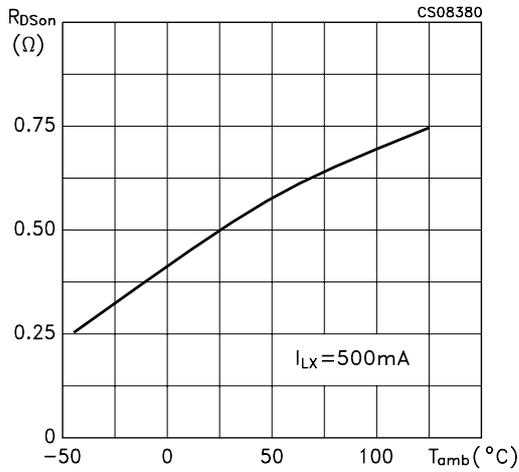


Figure 14 : LX On Resistance vs Input Voltage

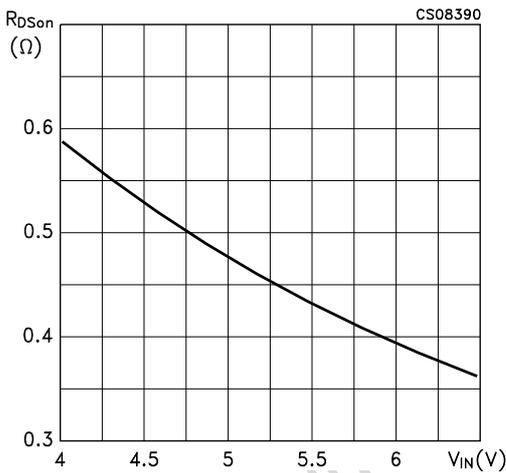


Figure 15 : Load Transient

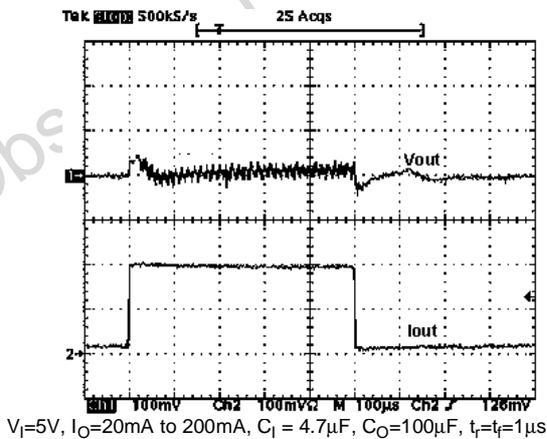


Figure 16 : Load Transient

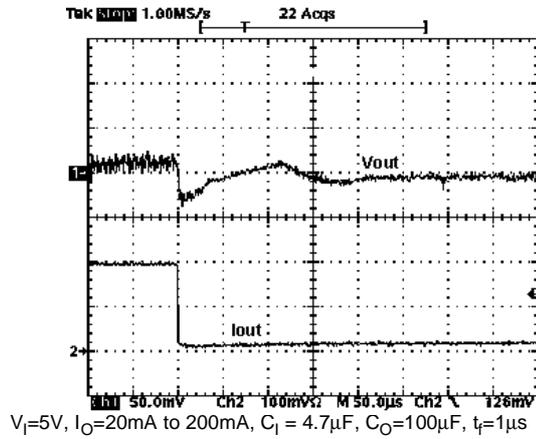


Figure 17 : Load Transient

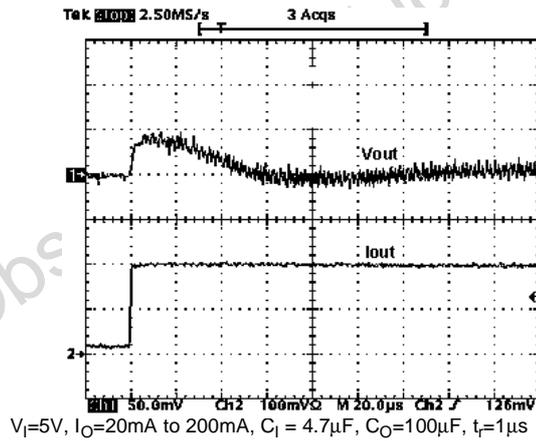
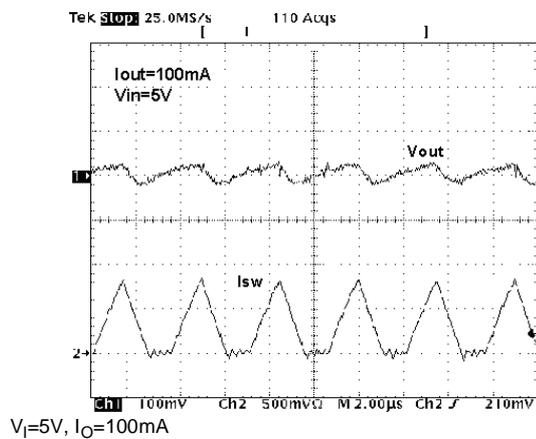
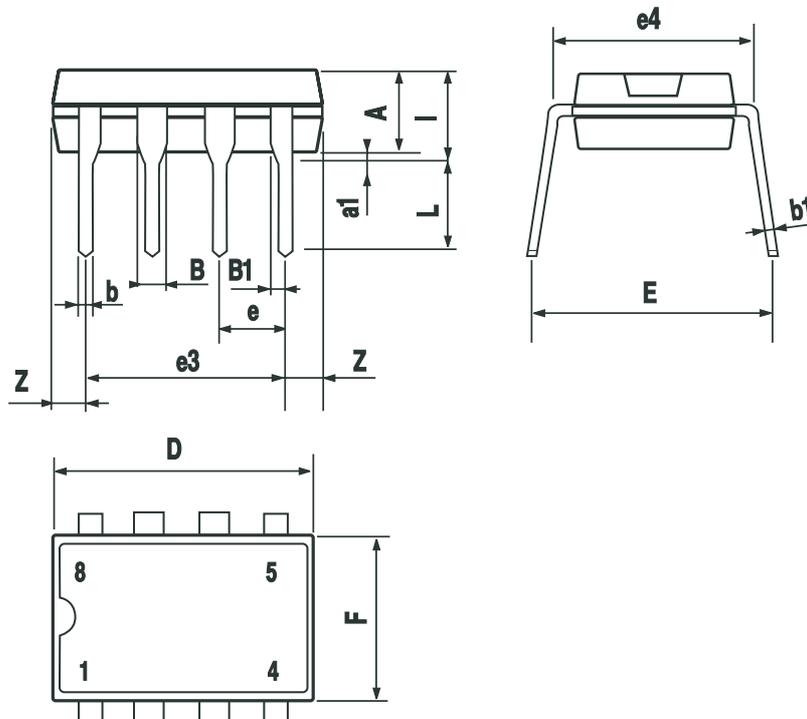


Figure 18 : Switching Waveform



Plastic DIP-8 MECHANICAL DATA

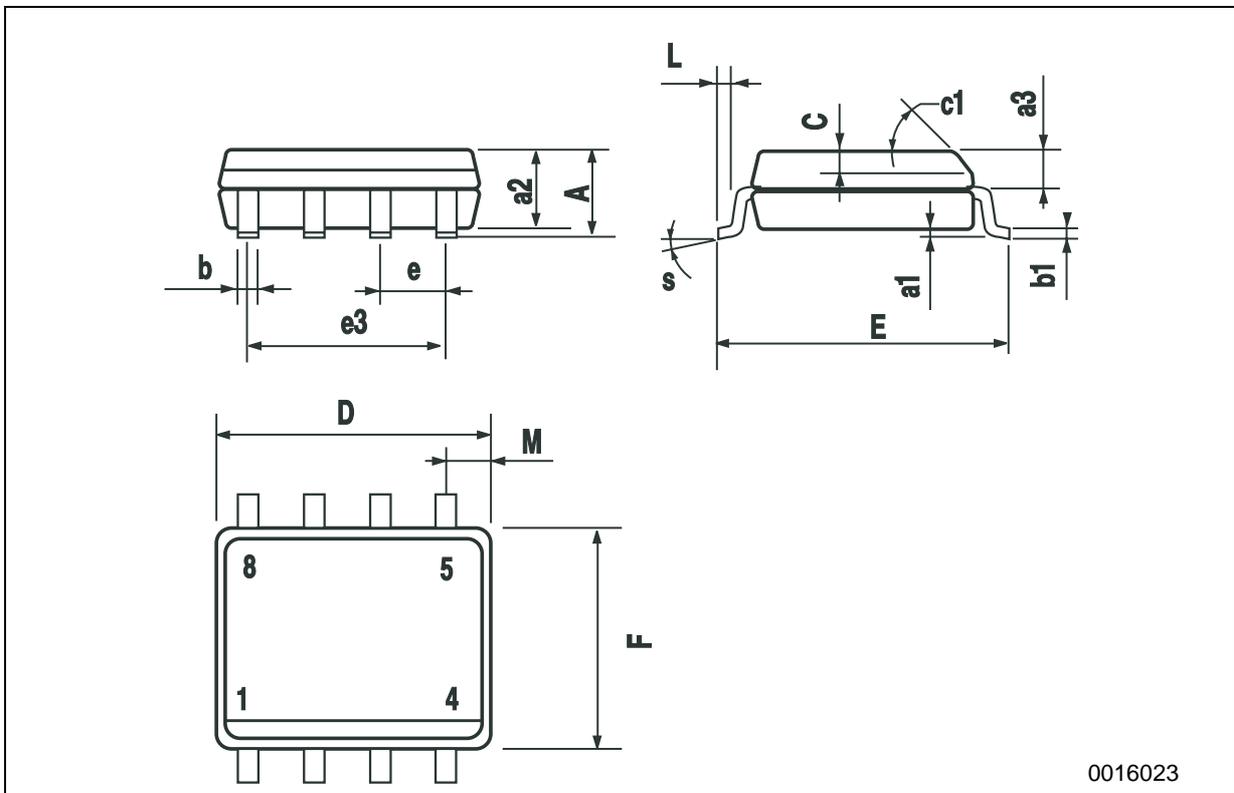
| DIM. | mm. | | | inch | | |
|------|------|------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | 3.3 | | | 0.130 | |
| a1 | 0.7 | | | 0.028 | | |
| B | 1.39 | | 1.65 | 0.055 | | 0.065 |
| B1 | 0.91 | | 1.04 | 0.036 | | 0.041 |
| b | | 0.5 | | | 0.020 | |
| b1 | 0.38 | | 0.5 | 0.015 | | 0.020 |
| D | | | 9.8 | | | 0.386 |
| E | | 8.8 | | | 0.346 | |
| e | | 2.54 | | | 0.100 | |
| e3 | | 7.62 | | | 0.300 | |
| e4 | | 7.62 | | | 0.300 | |
| F | | | 7.1 | | | 0.280 |
| l | | | 4.8 | | | 0.189 |
| L | | 3.3 | | | 0.130 | |
| Z | 0.44 | | 1.6 | 0.017 | | 0.063 |



P001F

SO-8 MECHANICAL DATA

| DIM. | mm. | | | inch | | |
|------|------------|------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 1.75 | | | 0.068 |
| a1 | 0.1 | | 0.25 | 0.003 | | 0.009 |
| a2 | | | 1.65 | | | 0.064 |
| a3 | 0.65 | | 0.85 | 0.025 | | 0.033 |
| b | 0.35 | | 0.48 | 0.013 | | 0.018 |
| b1 | 0.19 | | 0.25 | 0.007 | | 0.010 |
| C | 0.25 | | 0.5 | 0.010 | | 0.019 |
| c1 | 45° (typ.) | | | | | |
| D | 4.8 | | 5.0 | 0.189 | | 0.196 |
| E | 5.8 | | 6.2 | 0.228 | | 0.244 |
| e | | 1.27 | | | 0.050 | |
| e3 | | 3.81 | | | 0.150 | |
| F | 3.8 | | 4.0 | 0.149 | | 0.157 |
| L | 0.4 | | 1.27 | 0.015 | | 0.050 |
| M | | | 0.6 | | | 0.023 |
| S | 8° (max.) | | | | | |



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